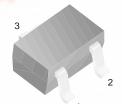


### **FJX4006R**

### Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R<sub>1</sub>=10KΩ, R<sub>2</sub>=47KΩ)
- Complement to FJX3006R

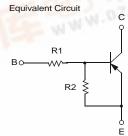


SOT-323

1. Base 2. Emitter 3. Collector







# PNP Epitaxial Silicon Transistor

### Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-10	V
С	Collector Current	-100	mA
P <sub>C</sub>	Collector Power Dissipation	200	mW
ТЈ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -10\mu A, I_E = 0$	-50		7 6 6	V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu A, I_B = 0$	-50	da-		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -40V, I <sub>E</sub> =0			-0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = -5V$ , $I_{C} = -5mA$	68	44.44		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_{C} = -10 \text{mA}, I_{B} = -0.5 \text{mA}$			-0.3	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0 f=1.0MHz		5.5		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -10V, I_{C} = -5mA$		200		MHz
V <sub>I</sub> (off)	Input Off Voltage	$V_{CE}$ = -5V, $I_{C}$ = -100 $\mu$ A	-0.3			V
V <sub>I</sub> (on)	Input On Voltage	$V_{CE}$ = -0.3V, $I_{C}$ = -1mA			-1.4	V
R <sub>1</sub>	Input Resistor		7	10	13	ΚΩ
R <sub>1</sub> /R <sub>2</sub>	Resistor Ratio		0.19	0.21	0.24	

# **Typical Characteristics**

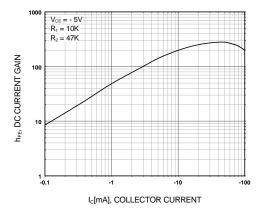


Figure 1. DC current Gain

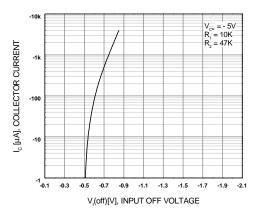


Figure 3. Input Off Voltage

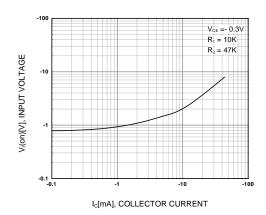


Figure 2. Input On Voltage

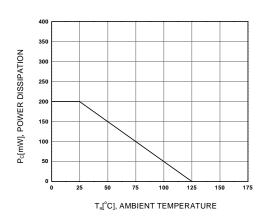


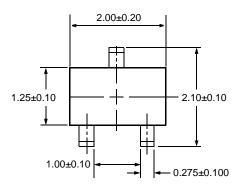
Figure 4. Power Derating

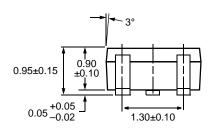
Rev. A3, August 2002

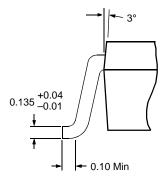
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# **Package Dimensions**

# SOT-323







Dimensions in Millimeters

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Bottomless™	FAST <sup>®</sup>	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	$QS^{TM}$	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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